Typical Applications Circuit
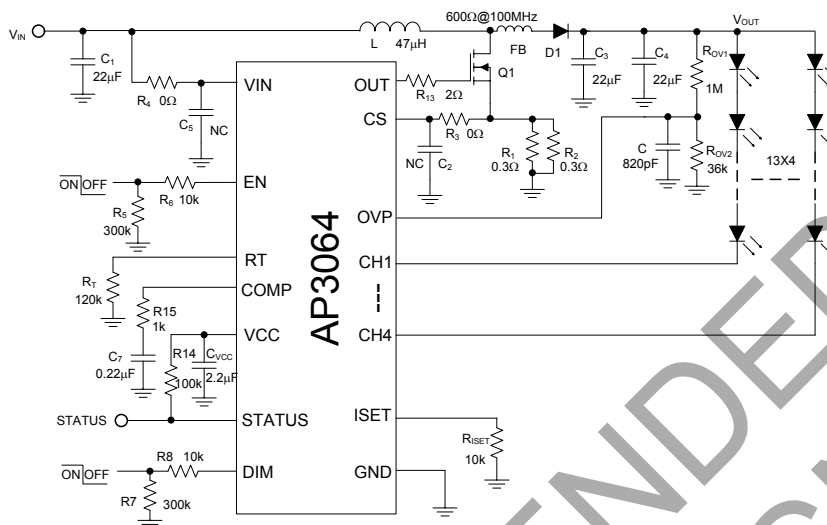
Pin Description

Pin Number	Pin Name	Function
1	CH4	LED current sink 4. Leave the pin open directly if not used
2	ISET	LED current setting pin. The corresponding maximum current of all 4 strings is set through connecting a resistor from this pin to GND
3	OVP	Over voltage protection pin. When the OVP pin voltage exceeds 2.0V, the OVP is triggered and the power switch is turned off. When the OVP pin voltage drops below hysteresis voltage, the OVP is released and the power switch will resume normal operation
4	RT	Frequency control pin
5	EN	ON/OFF control pin. Forcing this pin above 2.4V enables the IC while below 0.5V shuts down the IC. When the IC is in shutdown mode, all functions are disabled to decrease the supply current below 3µA
6	CS	Power switch current sense input
7	OUT	Boost converter power switch gate output. This pin output high voltage (5V/V_{IN}-0.5V) to drive the external N-MOSFET
8	VCC	5V linear regulator output pin. This pin should be bypassed to GND (recommend to connect with GND pin) with a ceramic capacitor
9	VIN	Supply input pin. A capacitor (typical 10µF) should be connected between the V_{IN} and GND to keep the DC input voltage constant
10	STATUS	LED operation status output
11	COMP	Soft-start and control loop compensation
12	DIM	PWM dimming control pin. Adding a PWM signal to this pin to control LED dimming. If not used, connect it to the high level
13	CH1	LED current sink 1. Leave the pin open directly if not used
14	CH2	LED current sink 2. Leave the pin open directly if not used
15	GND	Ground
16	CH3	LED current sink 3. Leave the pin open directly if not used

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Functional Block Diagram

VIN 9

BANDGAP 1.25V

EN 5

EN

REFERENCE 5V

VCC 8

100mV

3.2V

OVP 3

OVP

2V

LOGIC

STATUS 10

Diode/ Inductor Short

OTSD

CLK R S Q

DRIVE

OUT 7

GND 15

OCP 540mV

CS 6

SAW

PWM

COMP 11

EA Vch-reg

FB

RT 4

OSC

CLK

SAW

V_{CC}

V_{REF}

OPA

ISET 2

DIM 12

PWM Dimming

CH1 13

V_{CC}

Current Sink

Current Sink

CH2 14

Current Sink

CH3 16

Current Sink

CH4 1

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Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Value	Unit
V_{IN}	Input Voltage	-0.3 to 42	V
V_{CH}	CH1 to CH4 Voltage	-0.3 to 65	V
V_{EN}	EN Pin Voltage	-0.3 to 7	V
V_{CC}	VCC Pin Voltage	-0.3 to 7	V
V_{CS}	CS Pin Voltage	-0.3 to 7 (Note 5)	V
V_{COMP}	COMP Pin Voltage	-0.3 to 7	V
V_{ISET}	ISET Pin Voltage	-0.3 to 7	V
V_{OUT}	OUT Pin Voltage	-0.3 to 7	V
V_{OVP}	OVP Pin Voltage	-0.3 to 7	V
V_{RT}	RT Pin Voltage	-0.3 to 7	V
V_{STATUS}	STATUS Pin Voltage	-0.3 to 7	V
V_{DIM}	DIM Pin Voltage	-0.3 to 7	V
V_{GND}	GND Pin Voltage	-0.3 to 0.3	V
θ_{JA}	Thermal Resistance (Junction to Ambient) (Note 6)	79	°C/W
θ_{JC}	Thermal Resistance (Junction to Case) (Note 6)	10	°C/W
T_J	Operating Junction Temperature	+150	°C
T_{STG}	Storage Temperature	-65 to +150	°C
T_{LEAD}	Lead Temperature (Soldering, 10sec)	+260	°C
—	ESD (Machine Model)	200	V
—	ESD (Human Body Model)	2000	V

Notes: 4. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

5. Negative CS 100ns Transient maximum rating voltage reach to -0.4V.

6. Device mounted on 2"x2" FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V_{IN}	Input Voltage	4.5	33	V
f_O	Operating Frequency	0.1	1	MHz
V_{CHX}	LED Channel Voltage	—	60	V
I_{CHX}	LED Channel Current	20	220	mA
f_{PWM}	PWM Dimming Frequency	0.1	20	kHz
T_A	Operating Ambient Temperature Range	-40	+85	°C

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Electrical Characteristics (V$_{IN}$ = 24V, V$_{EN}$ = 5V, Typical T$_A$ = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
INPUT SUPPLY						
V$_{IN}$	Input Voltage	—	4.5	—	33	V
I$_Q$	Quiescent Current	No Switching	—	3	5	mA
I$_{SHTD}$	Shutdown Supply Current	V$_{EN}$ = V$_{DD}$ = 0V	—	0.1	3	µA
V$_{UVLO}$	UVLO	V$_{IN}$ Rising	3.6	3.8	4.0	V
V$_{HYS}$	UVLO Hysteresis	—	—	200	—	mV
VCC SECTION						
V$_{CC}$	VCC Voltage	V$_{IN}$ ≥ 5.5V	—	5	—	V
		V$_{IN}$ < 5.5V, Load = 10mA	—	V$_{IN}$-0.1	—	V
t$_{RISING}$	OUT Pin Rising Time (Note 7)	1nF Load	—	30	50	ns
t$_{FALLING}$	OUT Pin Falling Time (Note 7)	1nF Load	—	30	50	ns
—	Load Regulation (Note 7)	Load = 0 to 30mA	—	5	—	mV/mA
—	Line Regulation (Note 7)	V$_{IN}$ = 5.5 to 24V	—	0.3	—	mV/V
HIGH FREQUENCY OSCILLATOR						
f$_{OSC}$	Switch Frequency (Target: 10% Variation)	R$_T$ = 100kΩ	440	520	600	kHz
—	Switch Frequency Range	—	0.1	—	1	MHz
D$_{MAX}$	Maximum Duty Cycle	f = 500kHz	88	90	—	%
t$_{ON-TIME}$	Minimum On-time (Note 7)	f = 500kHz	—	200	—	ns
ENABLE LOGIC AND DIMMING LOGIC						
V$_{EN\_H}$	EN High Voltage	—	2.4	—	—	V
V$_{EN\_L}$	EN Low Voltage	—	—	—	0.5	V
V$_{DIM\_H}$	PWM Logic for External Dimming	—	2.5	—	–	V
V$_{DIM\_L}$		—	—	—	0.3	V
t$_{PWM\_MIN}$	PWM Dimming Minimum Pulse Width (Note 7)	—	—	3/f$_{OSC}$	—	µs
POWER SWITCH DRIVE						
V$_{LIMIT}$	Current Limit Threshold Voltage	—	480	540	600	mV
V$_{LIMIT2}$	D/L Short Threshold Voltage	—	720	800	880	mV
t$_{LEB}$	Current Sense LEB Time (Note 7)	—	80	100	150	ns
COMPENSATION AND SOFT START (COMP PIN)						
G$_{EA}$	Error Amplifier Trans-conductance	—	—	2300	—	µA/V
I$_{O\_H}$	Sourcing Current	V$_{COMP}$ = 0.5V	80	120	160	µA
I$_{O\_L}$	Sinking Current	V$_{COMP}$ = 2V	80	120	160	µA

Note: 7. Guaranteed by design.

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Electrical Characteristics (Cont. V_{IN} = 24V, V_{EN} = 5V, Typical T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OVER-VOLTAGE PROTECTION						
V_{OVP}	OVP Threshold Voltage	V_{OUT} Rising	1.9	2.0	2.1	V
V_{OVP_HYS}	OVP Hysteresis	—	—	250	—	mV
V_{OVP-SH}	Shutdown Under Abnormal Condition	—	3.0	3.2	3.4	V
CURRENT SOURCE						
I_{CH_MATCH}	LED Current Matching between Each String (Note 8)	I_{CH} = 100mA	—	1.5	4	%
I_{CH}	Regulation Current per Channel	R_{ISET} = 12kΩ	92	100	108	mA
V_{LED_REG}	Minimum LED Regulation Voltage	I_{CHX} = 100mA	—	230	—	mV
I_{LED_LEAK}	CH1 to CH4 Leakage Current	V_{EN} = 0V, V_{LED} = 37V	—	0.1	1	µA
V_{LED-S}	LED Short Protection Threshold	—	6.6	7.3	8.0	V
OVER-TEMPERATURE PROTECTION						
T_{OTSD}	Thermal Shutdown Temperature (Note 7)	—	—	+160	—	°C
T_{HYS}	Thermal Shutdown Recovery (Note 7)	—	—	+140	—	°C

Notes: 7. Guaranteed by design.

8. $I_{ST\_MATCH} = \dfrac{I_{MAX} - I_{MIN}}{2 \times I_{AVG}} \times 100\%$

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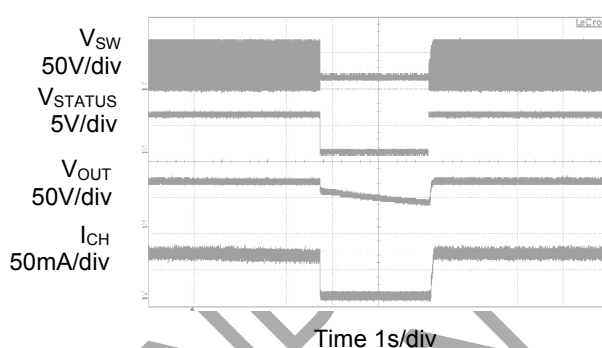
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Performance Characteristics (V_{IN} = 24V, V_{EN} = V_{DD} = 5V, 13 LEDs in series, 4 strings in parallel, 120mA/string, T_A = +25°C, unless otherwise specified.)

Frequency vs. R_T
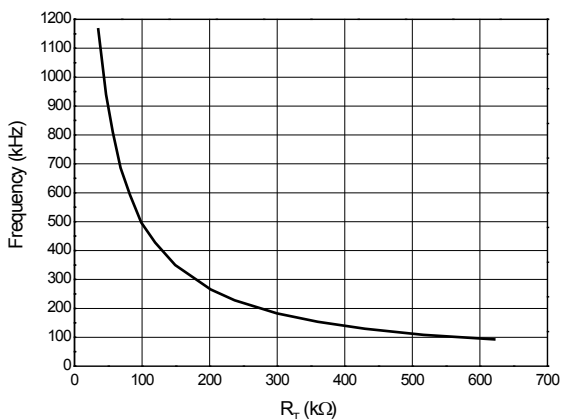
VCC Voltage vs. Input Voltage
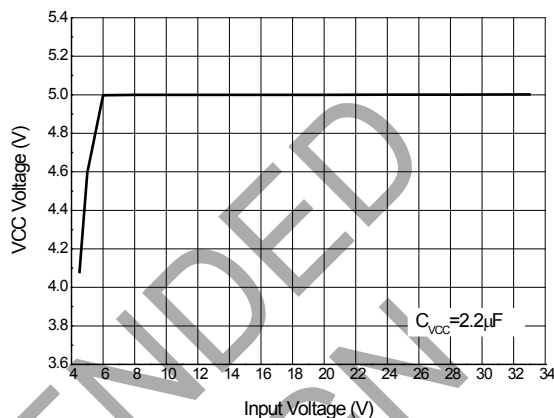
V_{CH} Regulation Voltage vs. Output Current
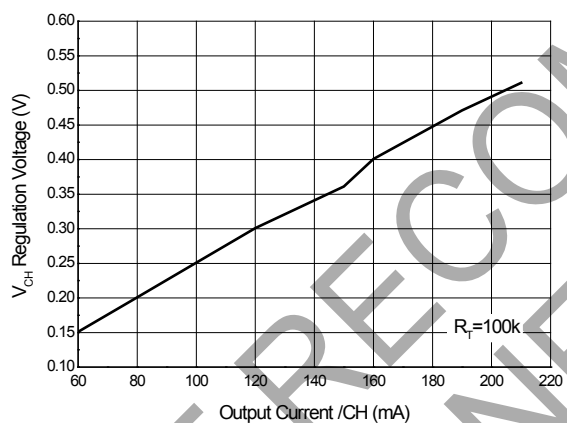
V_{CH} Regulation Voltage vs. Temperature
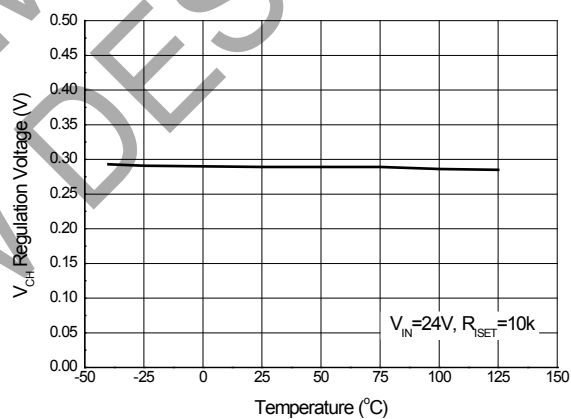
Channel Current vs. Channel
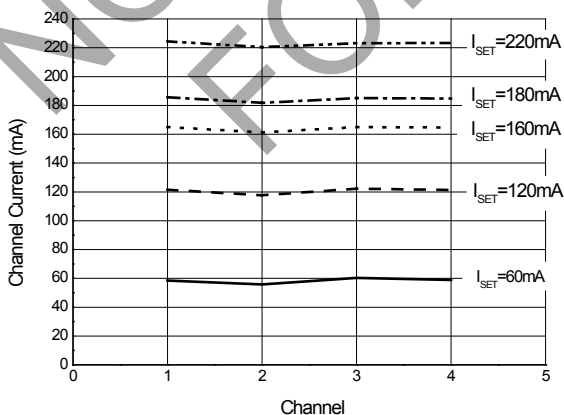
Efficiency vs. Output Current
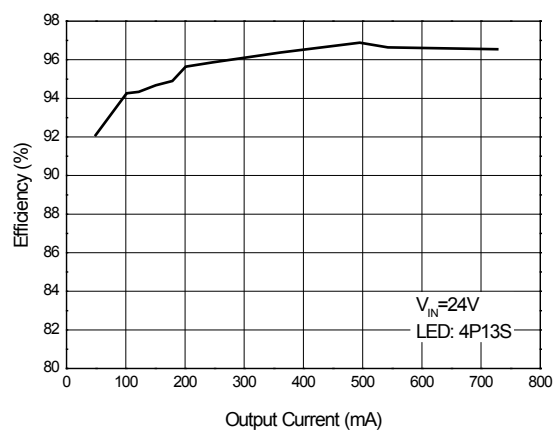
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Performance Characteristics (Cont. V_{IN} = 24V, V_{EN} = V_{DD} = 5V, 13 LEDs in series, 4 strings in parallel, 120mA/string, T_A = +25°C, unless otherwise specified.)

Steady State

V_{SW}
50V/div

I_{CH}
20mA/div

V_{OUT_AC}
500mV/div

V_{CH}
200mV/div

Time 1µs/div

System Startup

V_{IN}
20V/div

V_{SW}
20V/div

V_{OUT}
20V/div

I_{CH}
100mA/div
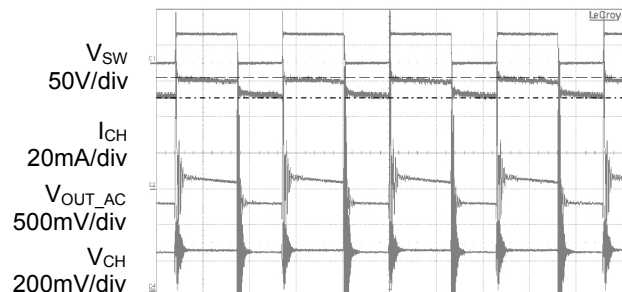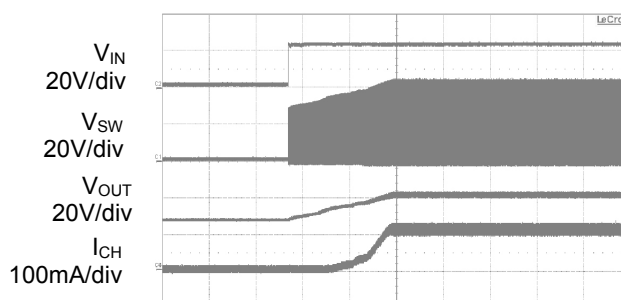
Time 20ms/div

PWM Dimming

V_{PWM}
5V/div

V_{SW}
20V/div

I_{CH}
100mA/div
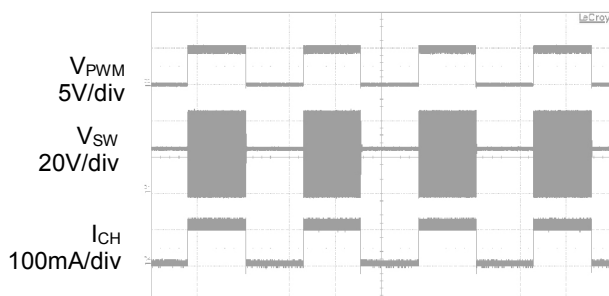
Time 2ms/div

LED Short Protection

V_{STATUS}
5V/div

V_{SW}
50V/div

I_{CH}
100mA/div

V_{CH}
5V/div
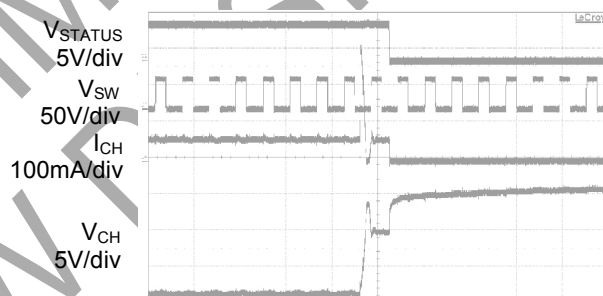
Time 10µs/div

LED Open Protection

V_{STATUS}
5V/div

V_{SW}
50V/div

I_{CH}
50mA/div

V_{OVP}
1V/div
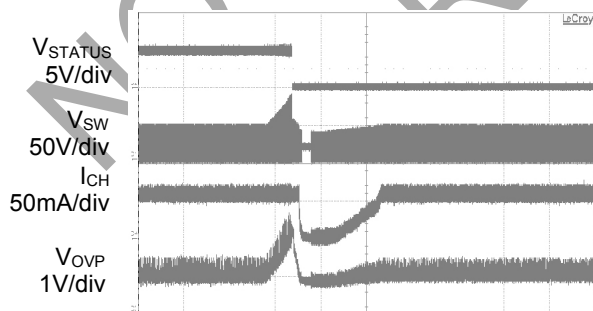
Time 50ms/div

Schottky/Inductor Short Protection
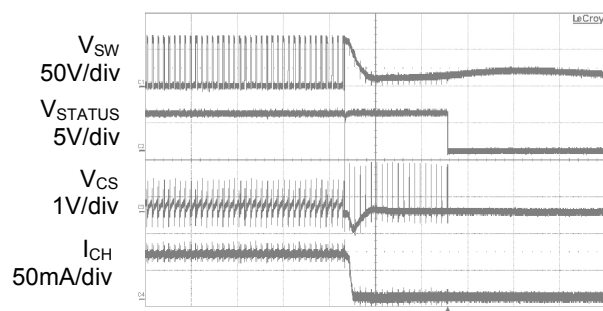
V_{SW}
50V/div

V_{STATUS}
5V/div

V_{CS}
1V/div

I_{CH}
50mA/div

Time 50µs/div

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Performance Characteristics (Cont. V_{IN} = 24V, V_{EN} = V_{DD} = 5V, 13 LEDs in series, 4 strings in parallel, 120mA/string, T_A = +25°C, unless otherwise specified.)

V_{OUT} Short/Diode Open Protection

V_{IN} 10V/div

V_{OVP} 5V/div

V_{GATE} 5V/div

I_{CH} 50mA/div

Time 5ms/div

Over Temperature Protection

V_{SW} 50V/div

V_{STATUS} 5V/div

V_{OUT} 50V/div

I_{CH} 50mA/div

Time 1s/div
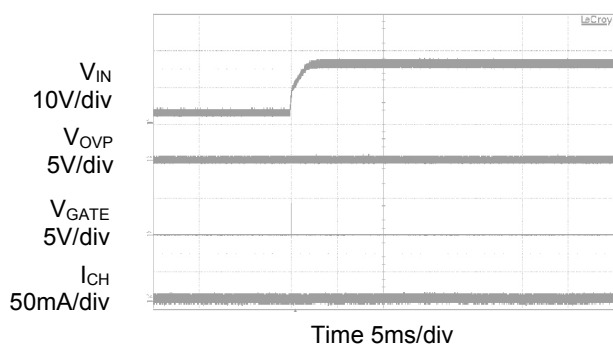
Application Information

1. Enable

The AP3064 is enabled when the voltage to EN is greater than approximately 2.4V, disabled when lower than 0.5V.

2. Frequency Selection

An external resistor R_T, placed between RT pin and GND, can be used to set the operating frequency. The operating frequency ranges from 100kHz to 1MHz. The high frequency operation optimizes the regulator for the smallest-sized component application, while low frequency operation can help to reduce switch loss. The approximate operating frequency can be expressed as below:

$$f_{OSC}[MHz] = \frac{52}{R_{RT}[K\Omega]}$$

3. LED Current Setting

The maximum LED current per channel can be adjusted up to 180mA via ISET pin. When ≥180mA current is needed in application, two or more channels can be paralleled to provide larger drive current. Connect a resistor R_{ISET} between ISET pin and GND to set the reference current I_{SET}. The LED current can be expressed as below:

$$I_{LED}[mA] = \frac{1200}{R_{ISET}[K\Omega]}$$

4. Dimming Control

Applying a PWM signal to DIM pin to adjust the LED current, that means, the LED current of all enabled channels can be adjusted at the same time and the LED brightness can be adjusted from 1%× I_{CHX_MAX} to 100%×I_{CHX_MAX}. During the "high level" period of PWM signal, the LED is turned on and 100% of the current flows through LED, while during the "low level" period of the PWM signal, the LED is turned off and almost no current flows through the LED, thus changing the average current through LED and finally adjusting LED brightness. The external PWM signal frequency applied to DIM pin is allowed to be 100Hz or higher.

5. Status Output

After IC is enabled, STATUS will output logic low if any of the following conditions exists:

(1) Any String is Open

(2) LED Short Circuit Protection

(3) Shut Down Under Abnormal Condition

(4) Over Voltage Protection

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Application Information (Cont.)

(5) Over Temperature Protection
(6) Schottky Diode Short Protection
(7) V_{OUT} Short/Open Schottky Diode Protection

6. Over Voltage Protection

The AP3064 integrates an OVP circuit. The OVP pin is connected to the center tap of voltage-divider (R_{OV1} and R_{OV2}) that placed between high voltage output and GND. If the voltage on OVP pin exceeds 2.0V, which may results from open loop or excessive output voltage, all the functions of AP3064 will be disabled with output voltage falling. The OVP hysteresis is 250mV. The formulas of OVP can be expressed as below:

$$V_{OVP} = \frac{(R_{OV1} + R_{OV2}) \times 2.0V}{R_{OV2}}$$

7. Over Current Protection

The AP3064 integrates an OCP circuit. The CS pin is connected to the voltage-sensor (R_{CS}) that placed between the Drain of MOS and GND. If the voltage on CS pin exceeds 0.54V, it is turned off immediately and will not turn on until the next cycle begins.

8. LED Short-Circuit Protection

The AP3064 integrates an LED Short-circuit protection circuit. If the voltage at any of the CH1-4 pins exceeds a threshold of approximately 7.3V during normal operation, the corresponding string is turned off and is latched off. Toggle V_{IN} and/or EN to reset the latch. LED short detecting logic priority is lower than open LED and OVP logic. The LED short detecting is triggered when $0.1V < V_{LED\_MIN}$ under dimming on mode, disabled when LED open occurs until output voltage resumes to the regulated voltage.

9. LED Open-circuit Protection

The AP3064 integrates an LED Open-circuit Protection circuit. When any LED string is open, V_{OUT} will boost up until the voltage at OVP pin reaches an approximate 2.0V threshold. The IC will automatically ignore the open string whose corresponding pin voltage is less than 100mV and the remaining string will continue operation. If all the strings are open and the voltage at OVP reaches a threshold of 2.0V, the MOSFET drive GATE will turn off and IC will shut down and latch.

10. V_{OUT} Short / Open Schottky Diode Protection

The AP3064 monitors the OVP pin, if the OVP pin voltage is less than 0.1V, MOSFET drive output will turn off. This protects the converter if the output Schottky diode is open or V_{OUT} is shorted to ground.

11. Under Voltage Lockout

The AP3064 provides an under voltage lockout circuit to prevent it from undefined status when startup. The UVLO circuit shuts down the device when V_{CC} drops below 3.6V. The UVLO circuit has 200mV hysteresis, which means the device starts up again when V_{CC} rise to 3.8V.

12. Over Temperature Protection

The AP3064 features Over Temperature Protection, if the junction temperature exceeds approximately +160°C, the IC will shut down until the junction temperature is less than approximately +140°C. When the IC is released from over temperature shutdown, it will start a soft-start process.

13. Schottky Diode/Inductor Short Circuit Protection

The AP3064 features Schottky diode/inductor short-circuit protection circuit. When CS pin voltage exceeds 0.8V for greater than 16 switching clocks, the IC will latch. The voltage of CS is monitored after a short delay of LEB.

14. Shut Down under Abnormal Condition

The AP3064 features shutdown under abnormal condition protection circuit. When OVP pin voltage exceeds 3.2V, the IC will latch. Toggle EN to restart the IC. This feature can be used for any other protection to shut down the IC.

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Ordering Information

AP3064 X XX - XX

Product Name	Package	Packing	RoHS/Green
	M : SO-16	TR : Tape & Reel	G1 : RoHS Compliant and Green
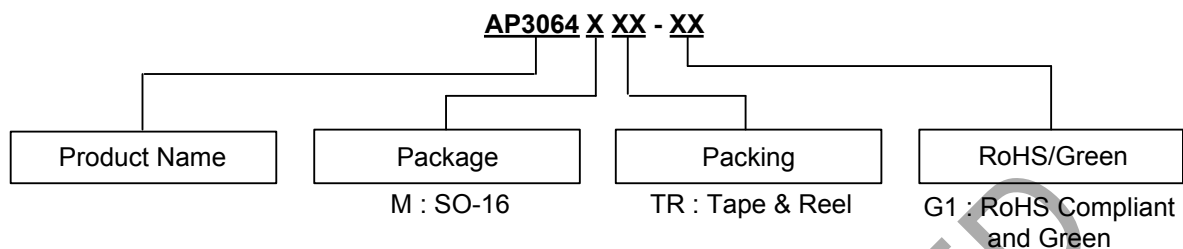
Package	Temperature Range	Part Number	Marking ID	Packing
SO-16	-40 to +85°C	AP3064MTR-G1	AP3064M-G1	4000/13" Tape & Reel

Marking Information

(Top View)

AP3064M-G1
YWWAXX
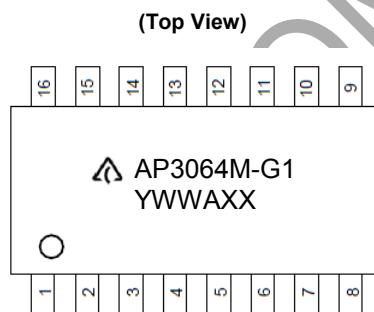
First Line: Logo and Marking ID
Second Line: Date Code
Y: Year
WW: Work Week of Molding
A: Assembly House Code
XX: 7th and 8th Digits of Batch Number

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.
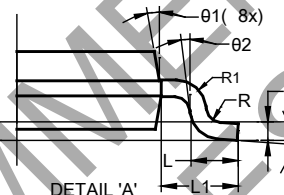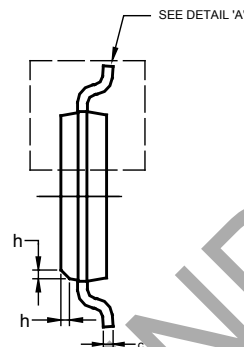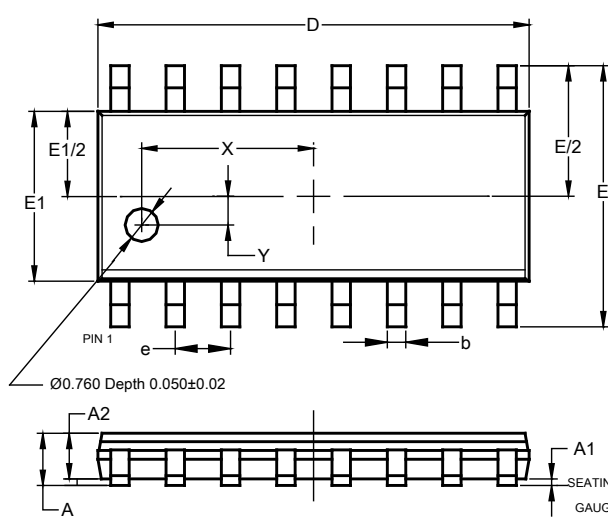
SO-16

SO-16			
Dim	Min	Max	Typ
A	--	1.260	--
A1	0.10	0.23	--
A2	1.02	--	--
b	0.31	0.51	--
c	0.10	0.25	--
D	9.80	10.00	--
E	5.90	6.10	--
E1	3.80	4.00	--
e	1.27 BSC		
h	0.15	0.25	0.20
L	0.40	1.27	--
L1	1.04 REF		
L2	0.25 BSC		
R	0.07	--	--
R1	0.07	--	--
X	3.945 REF		
Y	0.661 REF		
θ	0°	8°	--
θ1	5°	15°	--
θ2	0°	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-16
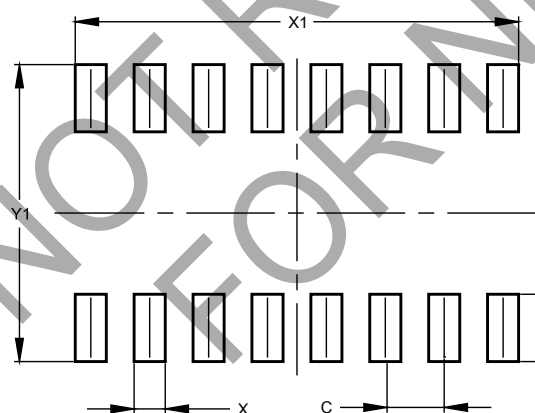
Dimensions	Value (in mm)
C	1.270
X	0.670
X1	9.560
Y	1.450
Y1	6.400

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IMPORTANT NOTICE

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